High Performance Schottky Rectifier, 2 x 10 A **FEATURES** 

- 175 °C T<sub>J</sub> operation
- · Center tap configuration
- Low forward voltage drop
- · High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

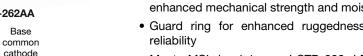
This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

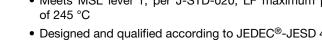
MAJOR RATINGS AND CHAR	MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I <sub>F(AV)</sub>	Rectangular waveform	20	А				
V <sub>RRM</sub>		150	V				
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1030	А				
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.66	V				
TJ	Range	-55 to +175	°C				

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-20CTQ150S-M3 VS-20CTQ150-1-M3	UNITS
Maximum DC reverse voltage	V <sub>R</sub>	150	V
Maximum working peak reverse voltage	V <sub>RWM</sub>	130	v

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VS





5-20C	<b>FQ150S</b>	5-M3, V	/S-20CT	Q150-	1-M3

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2

D<sup>2</sup>PAK (TO-263AB)

Base

common cathode

02

<u>ර</u> 2

1 Common 🗄 3

Anode cathode Anode

VS-20CTQ150S-M3

I<sub>F(AV)</sub>

VR

V<sub>F</sub> at I<sub>F</sub> I<sub>RM</sub> max.

T<sub>J</sub> max.

 $\mathsf{E}_{\mathsf{AS}}$ 

Package

Circuit configuration

PRIMARY CHARACTERISTICS

3

**TO-262AA** 

Base

02

0 2

10 Common 0 3

Anode cathode Anode

VS-20CTQ150-1-M3

2 x 10 A

150 V

0.66 V

5.0 mA at 125 °C

175 °C

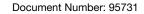
1.0 mJ D<sup>2</sup>PAK (TO-263AB), TO-262AA

Common cathode



**Vishay Semiconductors** 

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ABSOLUTE MAXIMUM RA	TINGS				
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS
÷ .	r leg			10	
current See fig. 5 per de	vice I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 154 °C	C, rectangular waveform	20	А
Maximum peak one cycle	_	5 µs sine or 3 µs rect. pulse	Following any rated	1030	A
non-repetitive surge current per leg See fig. 7	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	load condition and with rated V <sub>RRM</sub> applied	180	
Non-repetitive avalanche energy per	eg E <sub>AS</sub>	$T_J$ = 25 °C, $I_{AS}$ = 1 A, L = 2 mH		1.0	mJ
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zer Frequency limited by $T_J$ maxim		1	А

ELECTRICAL SPECIFICATIONS	;					
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS
		10 A	T.I = 25 °C	0.80	0.88	
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	20 A	1j=25 C	0.90	1.0	V
See fig. 1	VFM (")	10 A	T.I = 125 °C	0.63	0.66	v
		20 A	1J = 125 C	0.73	0.77	
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	3.0	25	μA
See fig. 2	IRM (")	T <sub>J</sub> = 125 °C	$v_{\rm R} = haleu v_{\rm R}$	2.7	5.0	mA
Typical junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal rang	ge 100 kHz to 1 MHz), 25 °C	-	280	pF
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 m	m from package body	-	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		-	10 000	V/µs

### Note

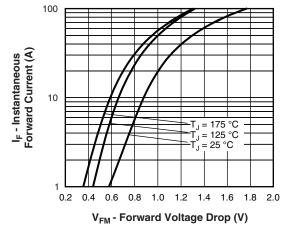
 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

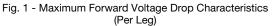
THERMAL - MECHAN	THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS			
Maximum junction and storag temperature range	e	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			
Maximum thermal resistance,	per leg	D	DC operation	2.0				
junction to case	per package	R <sub>thJC</sub>	DC operation	1.0	°C/W			
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased (Only for TO-262)	0.50	0,11			
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
		Case style D <sup>2</sup> PAK (TO-263AB)		20CTQ150S				
Marking device			Case style TO-262AA	20CTQ	150-1			

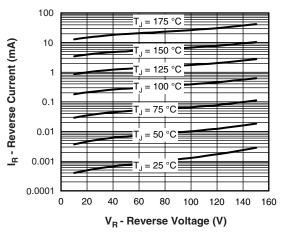


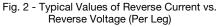
# VS-20CTQ150S-M3, VS-20CTQ150-1-M3

**Vishay Semiconductors** 









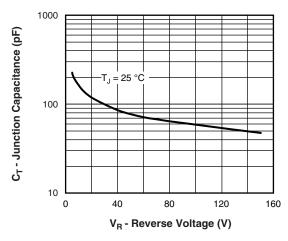
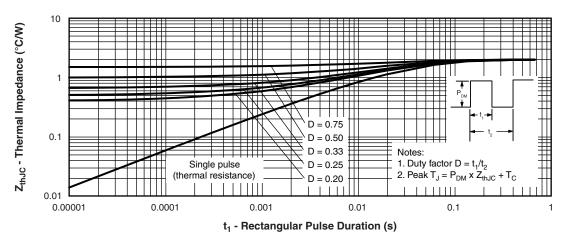
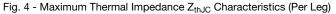


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)





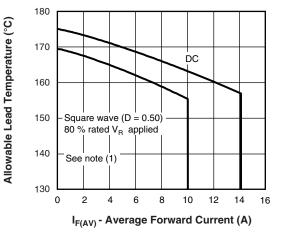
 Bevision: 21-Dec-2021
 Document Number: 95731

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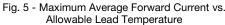
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# VS-20CTQ150S-M3, VS-20CTQ150-1-M3





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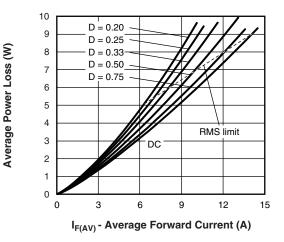


Fig. 6 - Maximum Average Forward Dissipation vs. Average Forward Current

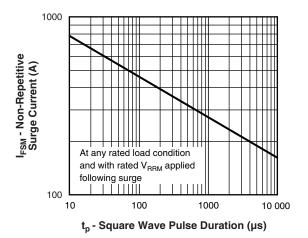


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

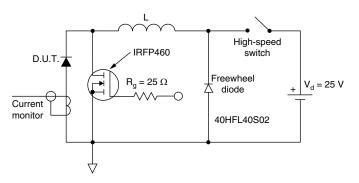


Fig. 8 - Unclamped Inductive Test Circuit

### Note

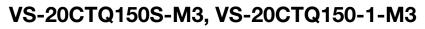
<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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4

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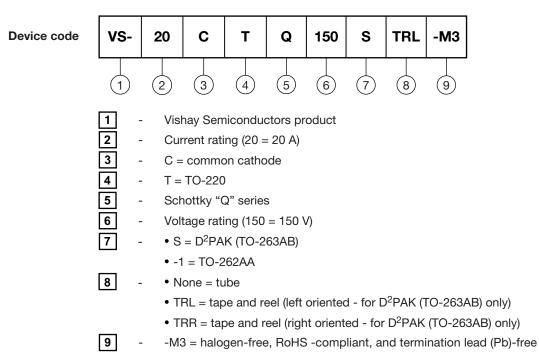


### **Vishay Semiconductors**

### **ORDERING INFORMATION TABLE**

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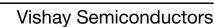
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ORDERING INFORMATION (Example)						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-20CTQ150S-M3	50	Antistatic plastic tubes				
VS-20CTQ150STRL-M3	800	13" diameter plastic tape and reel				
VS-20CTQ150STRR-M3	800	13" diameter plastic tape and reel				
VS-20CTQ150-1-M3	50	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS						
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164				
Dimensions	TO-262AA	www.vishay.com/doc?96165				
Part marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information		www.vishay.com/doc?96424				

# **Outline Dimensions**

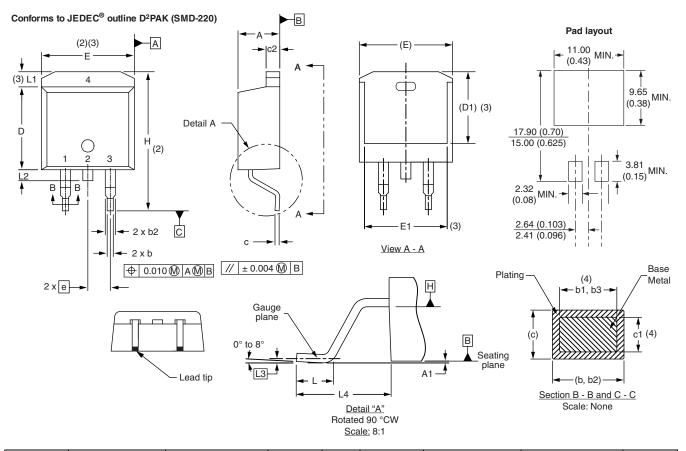


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D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches

SHA



SYMBOL	MILLIMETERS		INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	е	2.54	BSC	0.100	) BSC	
b2	1.14	1.78	0.045	0.070		Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065		L3	0.25	BSC	0.010	) BSC	
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

Revision: 08-Jul-15

1

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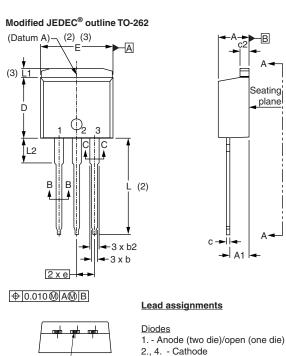
# **Outline Dimensions**



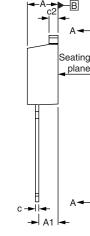
**Vishay Semiconductors** 

**TO-262** 

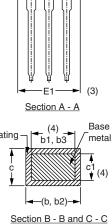
### **DIMENSIONS** in millimeters and inches



Lead tip -



E1 Plating



Е

D1(3)

Scale: None

SYMBOL	MILLIM	ETERS	INC	NOTES	
STNIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	2.54 BSC		) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.36	3.71	0.132	0.146	

3. - Anode

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches (6)

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body <sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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1

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